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PC852XJ0000F Series PC853XJ0000F Series

DIP 4pin Darlington Phototransistor Ouput, High Collector-emitter Voltage Photocoupler



■ Description

PC852XJ0000F Series/PC853XJ0000F Series contains an IRED optically coupled to a phototransistor.

It is packaged in a 4-pin DIP, available in SMT gullwing lead-form option.

Input-output isolation voltage(rms) is 5.0kV.

Collector-emitter voltage is 350V and CTR is MIN. 1 000% at input current of 1mA.

■ Features

- 1. 4pin DIP package
- Double transfer mold package (Ideal for Flow Soldering)
- 3. High collector-emitter voltage (V_{CEO}: 350V)
- 4. Durlington phototransistor output (CTR : MIN. 1 000% at $I_F=1mA$, $V_{CE}=2V$)
- Large collector power disspation : PC853XJ0000F (P_C : 300mW)
- 6. High isolation voltage between input and output (V_{iso(rms)}: 5kV)
- 7. Lead-free and RoHS directive compliant

■ Agency approvals/Compliance

- Recognized by UL1577, file No. E64380 (as model No. PC852/PC853)
- 2. Approved by VDE, DIN EN60747-5-2^(*) (only for PC852XJ0000F series as an option), file No. 40008087 (as model No. PC852)
- 3. Package resin: UL flammability grade (94V-0)

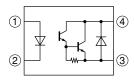
(*)DIN EN60747-5-2: successor standard of DIN VDE0884

■ Applications

- 1. Telephone line interface/isolation
- 2. Interface to power supply circuit
- 3. Controller for SSRs, DC motors



■ Internal Connection Diagram

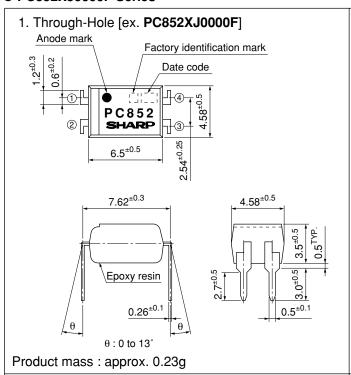


- 1) Anode
- ③ Cathode
- (4) Emitter
- ⑤ Collector

■ Outline Dimensions

(Unit: mm)

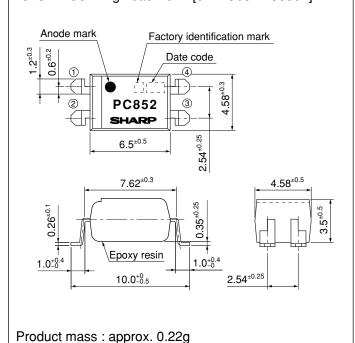
PC852XJ0000F Series



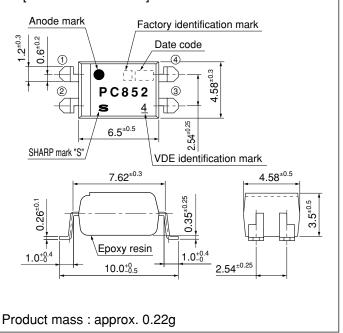
2. Through-Hole (VDE option) [ex. PC852XYJ000F] Anode mark Factory identification mark 0.6^{±0.2} Date code H. 10 PC852 2 [||3- $6.5^{\pm0.5}$ SHARP mark "S" VDE identification mark $7.62^{\pm0.3}$ 4.58^{±0.5} 0.5^{TYP.} Epoxy resin 0.5^{±0.1} 0.26^{±0.1} θ : 0 to 13°

Product mass: approx. 0.23g

3. SMT Gullwing Lead-Form [ex. PC852XIJ000F]



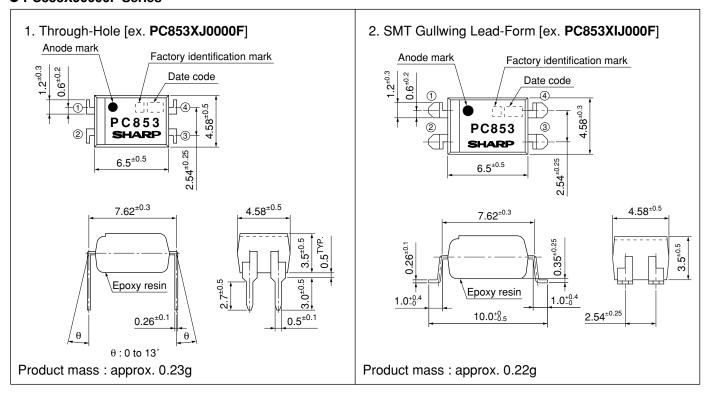
4. SMT Gullwing Lead-Form (VDE option) [ex. **PC852XPYJ00F**]



Plating material: SnCu (Cu: TYP. 2%)



● PC853XJ0000F Series (Unit : mm)





Date code (2 digit)

	1st o	digit		2nd digit		
	Year of p	roduction		Month of production		
A.D.	Mark	A.D	Mark	Month	Mark	
1990	A	2002	P	January	1	
1991	В	2003	R	February	2	
1992	С	2004	S	March	3	
1993	D	2005	T	April	4	
1994	Е	2006	U	May	5	
1995	F	2007	V	June	6	
1996	Н	2008	W	July	7	
1997	J	2009	X	August	8	
1998	K	2010	A	September	9	
1999	L	2011	В	October	0	
2000	M	2012	С	November	N	
2001	N	:	:	December	D	

repeats in a 20 year cycle

Factory identification mark

Factory identification Mark	Country of origin	
no mark	T	
	Japan	
	Indonesia	
_	China	

^{*} This factory marking is for identification purpose only.

Please contact the local SHARP sales representative to see the actural status of the

Rank mark

There is no rank mark indicator.



■ Absolute Maximum Ratings

 $(T_a=25^{\circ}C)$

Parameter		Symbol	Rating PC852XJ0000F PC853XJ0000F		Unit
	Forward current	I_{F}	5	0	mA
Input	*1 Peak forward current	I_{FM}	1	L	A
Inj	Reverse voltage	V_R	(5	V
	Power dissipation	P	7	0	mW
	Collector-emitter voltage	V_{CEO}	350		V
Jutput	Emitter-collector voltage	V_{ECO}	0.1		V
Out	Collector current	I_C	150		mA
	Collector power dissipation	P_{C}	150	300	mW
-	Total power dissipation	P_{tot}	200	320	mW
*2 Isolation voltage		V _{iso (rms)}	5.0		kV
Operating temperature		T_{opr}	-30 to +100		°C
Storage temperature		T_{stg}	-55 to +125		°C
*3 (Soldering temperature	T_{sol}	260		°C

■ Electro-optical Characteristics

 $(T_a=25^{\circ}C)$

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
'	Forward voltage		V_F	$I_F=10mA$	-	1.2	1.4	V
Input	Reverse voltage		I_R	$V_R=4V$	-	-	10	μΑ
	Terminal capa	acitance	C_{t}	V=0, f=1kHz	-	30	250	pF
Output	Collector dark	k current	I_{CEO}	$V_{CE}=200V, I_{F}=0$	_	_	200	nA
Output	Collector-emitter breakdown voltage		$BV_{CEO} \\$	$I_{C}=0.1 \text{mA}, I_{F}=0$	350	-	-	V
	Collector current		I_{C}	$I_F=1mA$, $V_{CE}=2V$	10	40	150	mA
	Collector-emitter saturation voltage		$V_{\text{CE (sat)}}$	$I_F=20mA, I_C=100mA$	-	-	1.2	V
Transfer	Isolation resistance		$R_{\rm ISO}$	DC500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	-	Ω
charac-	Floating capacitance		C_{f}	V=0, $f=1MHz$	-	0.6	1.0	pF
teristics	Cut-off frequency		f_C	V_{CE} =2V, I_{C} =20mA, R_{L} =100 Ω , -3dB	1	7	-	kHz
	Response time	Rise time	t_r	V_{CE} =2V, I_{C} =20mA, R_{L} =100 Ω	_	100	300	μs
	Response time	Fall time	t_{f}		_	20	100	μs

^{*1} Pulse width≤100μs, Duty ratio : 0.001 *2 40 to 60%RH, AC for 1 minute, f=60Hz *3 For 10s



■ Model Line-up

● PC852XJ0000F Series

Lead Form	Through-Hole			SMT Gullwing		
Package	Sleeve			Taping		
1 ackage	100pcs/sleeve			2 000pcs/reel		
DIN EN60747-5-2	—— Approved				Approved	
Model No.	PC852XJ0000F	PC852XYJ000F	PC852XIJ000F	PC852XPJ000F	PC852XPYJ00F	

● PC853XJ0000F Series

Lead Form	Through-Hole	SMT G	ullwing	
Package	Sle	Taping		
1 ackage	100pcs	2 000pcs/reel		
DIN EN60747-5-2				
Model No.	PC853XJ0000F	PC853XIJ000F	PC853XPJ000F	

Please contact a local SHARP sales representative to inquire about production status.



Fig.1 Forward Current vs. Ambient Temperature

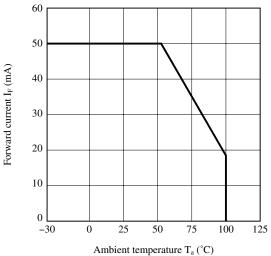


Fig.3-a Collector Power Dissipation vs.
Ambient Temperature

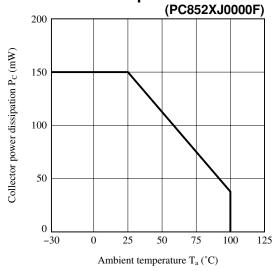


Fig.4 Total Power Dissipation vs. Ambient Temperature

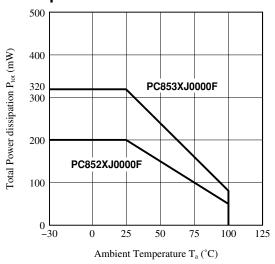


Fig.2 Diode Power Dissipation vs.
Ambient Temperature

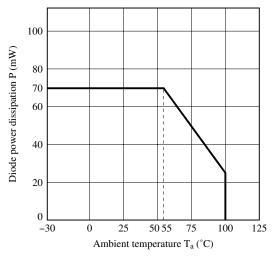


Fig.3-b Collector Power Dissipation vs.
Ambient Temperature

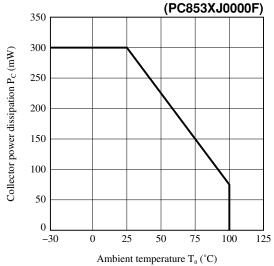


Fig.5 Peak Forward Current vs. Duty Ratio

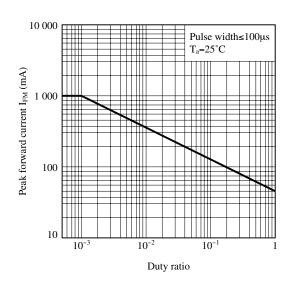




Fig.6 Forward Current vs. Forward Voltage

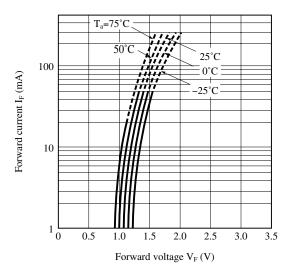


Fig.7-b Current Transfer Ratio vs. Forward

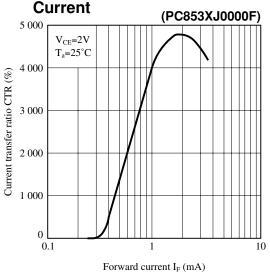


Fig.8-b Collector Current vs. Collectoremitter Voltage (POSSAY 19999E)

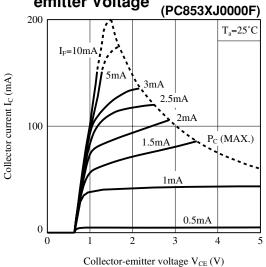


Fig.7-a Current Transfer Ratio vs. Forward
Current

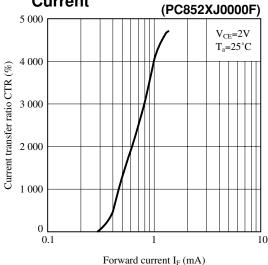


Fig.8-a Collector Current vs. Collectoremitter Voltage (PC852XJ0000F)

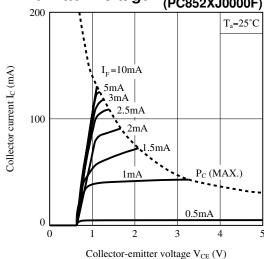


Fig.9 Relative Current Transfer Ratio vs. Ambient Temperature

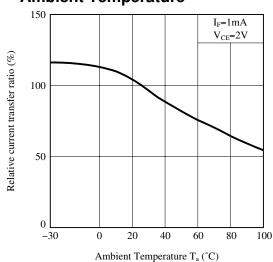




Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

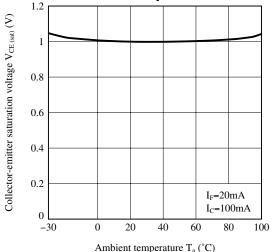


Fig.12 Response Time vs. Load Resistance

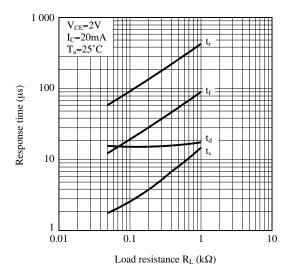


Fig.14 Frequency Response

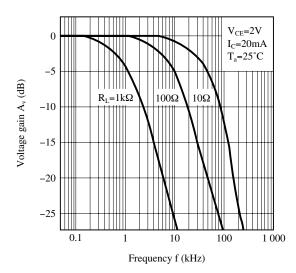


Fig.11 Collector Dark Current vs. Ambient Temperature

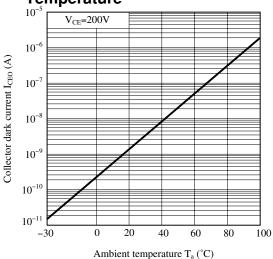
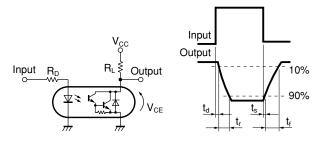
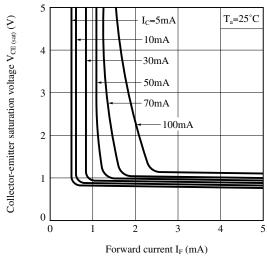


Fig.13 Test Circuit for Response Time



Please refer to the conditions in Fig.12.

Fig.15 Collector-emitter Saturation Voltage vs. Forward Current



Remarks: Please be aware that all data in the graph are just for reference and not for guarantee.



■ Design Considerations

Design guide

While operating at I_F<1.0mA, CTR variation may increase.

Please make design considering this fact.

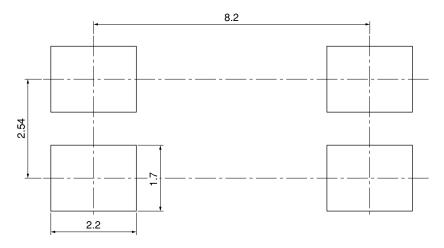
This product is not designed against irradiation and incorporates non-coherent IRED.

Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

Recommended Foot Print (reference)



(Unit:mm)

[☆] For additional design assistance, please review our corresponding Optoelectronic Application Notes.



■ Manufacturing Guidelines

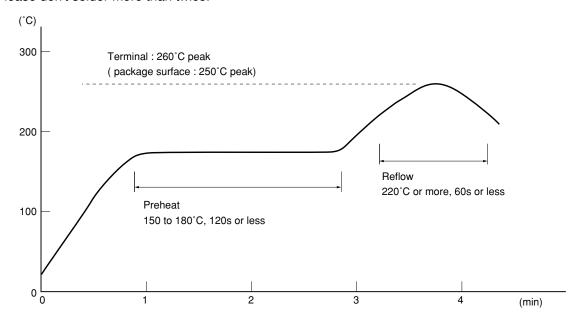
Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



Flow Soldering:

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below Immersion time should be 3 minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).



■ Package specification

Sleeve package

Package materials

Sleeve: HIPS (with anti-static material)

Stopper: Styrene-Elastomer

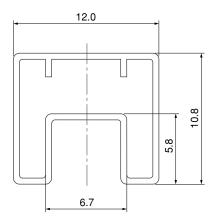
Package method

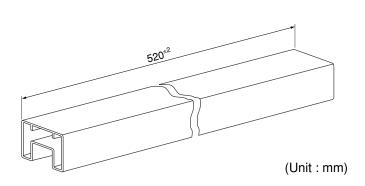
 $MAX.\ 100pcs\ of\ products\ shall\ be\ packaged\ in\ a\ sleeve.\ Both\ ends\ shall\ be\ closed\ by\ tabbed\ and\ tabless\ stoppers.$

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions







● Tape and Reel package

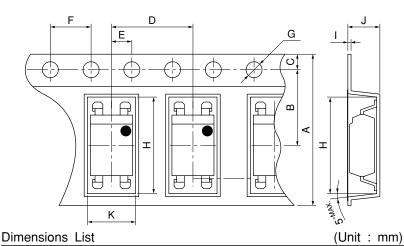
Package materials

Carrier tape : PS

Cover tape: PET (three layer system)

Reel: PS

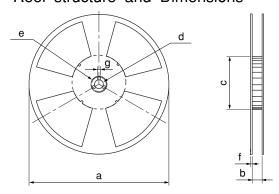
Carrier tape structure and Dimensions



Differsions List							
A	В	C	Ι				
1.6 0+0.3	7 5+0 1	1.75+0.1	0.0				

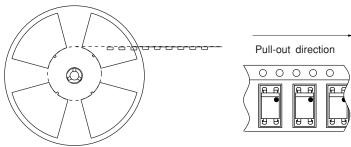
	ъ	C	D	L	1	<u> </u>
16.0±0.3	7.5 ^{±0.1}	1.75 ^{±0.1}	8.0 ^{±0.1}	2.0 ^{±0.1}	4.0 ^{±0.1}	φ1.5 ^{+0.1}
Н	I	J	K			
10.4 ^{±0.1}	0.4±0.05	4.2 ^{±0.1}	5.1 ^{±0.1}			

Reel structure and Dimensions



Dimensio	ns List	(Unit: mm)		
a	b	c	d	
330	330 17.5 ^{±1.5}		13 ^{±0.5}	
e	f	g		
23±1.0	2.0 ^{±0.5}	2.0 ^{±0.5}		

Direction of product insertion



[Packing: 2000pcs/reel]



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 - --- Office automation equipment
 - --- Telecommunication equipment [terminal]
 - --- Test and measurement equipment
 - --- Industrial control
 - --- Audio visual equipment
 - --- Consumer electronics
- (ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection

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- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.
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[E203] Sheet No.: D2-A04002EN